Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	254	arm same (dop\$3 with silicon )	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/25 15:55
L2	235271	arm with actuat\$6	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/25 15:33
L3	236647	arm\$1 with actuat\$6	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/25 15:33
L4	77	I1 and I3	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/25 15:41
L5	81	I1 and (piezoelectric\$6 or peizoelectric\$6 or peizo-electric\$6)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/25 15:52
L6	24	14 not 15	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/25 15:41
L7	149	l1 not (l4 or l5)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/25 15:44
L8	2	((arm\$1 with separat\$6 with substrate\$1) or (arm\$1 with opposite with sides with substrate\$1) or (arm\$1 with each with side with substrate\$1)) and (arm\$1 with (silicon or si) with (dop\$4 or conduct\$4 or (lower near4 (resistivity or resistance)))) and (piezoelectric\$6 or peizoelectric\$6 or piezo-electric\$6)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/25 15:54

L9	5323	arm same ((conduct\$4 or dop\$3) with (silicon or si))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/25 15:56
L10	17	I9 and ("360"/\$.\$).ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/25 16:25
L11	215	(microactuat\$4 or micro-actuat\$4) and ((arm\$1 or beam\$1) with (separat\$4 or between or inbetween or in-between) with substrate\$1)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/25 16:27
L12	323	(microactuat\$4 or micro-actuat\$4) and ((arm\$1 or beam\$1) with (separat\$4 or between or inbetween or in-between) with (substrate\$1 or base\$1 or spacer\$1))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/25 16:28
L13	143	I12 and ((arm\$1 or beam\$1) with (silicon or si or doped-silicon or doped-si))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/25 16:32
L14	30	I13 and ((beam\$1 or arm\$1) with (piezoelectric\$4 or peizoelectric\$4 or piezo-electric\$4))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/25 16:36
L15	208	(360/294.4).CCLS.	US-PGPUB; USPAT	OR	OFF	2005/09/25 16:37
L16	3	I15 and (dop\$3 with (si or silicon))	US-PGPUB; USPAT	OR	OFF	2005/09/25 16:38